Diode Semiconductor Device - Page 1 of 1



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#### **Inclosure Material:**

Metal

#### **Overall Length:**

1.453 inches

## **Mounting Facility Quantity:**

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Do-5

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.667 inches and 0.687 inches

#### Thread Size:

#### 0.250 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 reverse voltage, peak and 480.0 nonrepetitive peak reverse voltage

## **Current Rating Per Characteristic:**

35.00 amperes forward current, average absolute

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

## **Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

# **Specification Data:**

818349-mil-prf-19500/297 government specification

## Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0

# Mil-std (military Standard):

Mil-prf-19500 spec.